# onsemi

### PNP Low Saturation Transistor

**FZT790A** 

#### Description

These devices are designed with high current gain and low saturation voltage with collector currents up to 3 A continuous.

#### Features

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### ABSOLUTE MAXIMUM RATINGS (Notes 1, 2)

(Values are at  $T_A = 25^{\circ}C$  unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Emitter-Base Voltage	V <sub>EBO</sub>	-5	V
Collector Current – Continuous	Ι <sub>C</sub>	-3	А
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	–55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are based on a maximum junction temperature of 150°C.

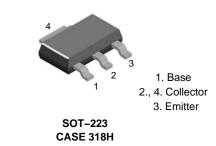
 These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty-cycle operations.

#### THERMAL CHARACTERISTICS (Note 3)

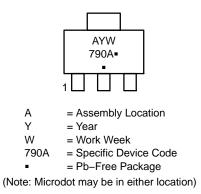
(Values are at  $T_A = 25^{\circ}C$  unless otherwise noted)

Parameter	Symbol	Value	Unit
Total Power Dissipation	PD	2	W
Dissipation Derate Above 25°C	PD	16	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	62.5	°C/W

 PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.



#### MARKING DIAGRAM



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

#### ELECTRICAL CHARACTERISTICS

(Values are at  $T_A = 25^{\circ}C$  unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Max.	Unit
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_{\rm C} = -10 \text{ mA}, I_{\rm B} = 0$	-40		V
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = -100 \ \mu A, \ I_{E} = 0$	-50		V
$BV_{EBO}$	Emitter–Base Breakdown Voltage	$I_{\rm E} = -100 \ \mu {\rm A}, \ I_{\rm C} = 0$	-5.0		V
I <sub>CBO</sub>	Collector Cut–Off Current	$V_{CB} = -30 \text{ V}, I_E = 0$		-100	nA
		$V_{CB} = -30 \text{ V}, I_E = 0, T_A = 100^{\circ}\text{C}$		-10	μΑ
I <sub>EBO</sub>	Emitter Cut–Off Current	$V_{EB} = -4 V, I_{C} = 0$		-100	nA
h <sub>FE</sub>	DC Current Gain (Note 4)	$V_{CE} = -2.0 \text{ V}, I_C = -10 \text{ mA}$	300		
		$V_{CE} = -2.0 \text{ V}, I_C = -500 \text{ mA}$	250		1
		$V_{CE} = -2.0 \text{ V}, I_{C} = -1.0 \text{ A}$	200		1
		$V_{CE} = -2.0 \text{ V}, I_C = -2.0 \text{ A}$	150		
V <sub>CE</sub> (sat)	Collector–Emitter Saturation Voltage	$I_{\rm C} = -500$ mA, $I_{\rm B} = -5.0$ mA		-0.25	V
	(Note 4)	$I_{\rm C} = -1.0$ A, $I_{\rm B} = -10$ mA		-0.45	
		$I_{\rm C} = -2.0$ A, $I_{\rm B} = -50$ mA		-0.75	
V <sub>BE</sub> (sat)	Base–Emitter Saturation Voltage (Note 4)	$I_{\rm C} = -1.0$ A, $I_{\rm B} = -10$ mA		-1.0	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage (Note 4)	$I_{C} = -1.0 \text{ A}, V_{CE} = -2.0 \text{ V}$		-1.0	V
f <sub>T</sub>	Transition Frequency	$I_{C} = -50$ mA, $V_{CE} = -5.0$ V, f = 50 MHz	100		MHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse test: pulse width  $\leq$  300 µs, duty cycle  $\leq$  2.0%

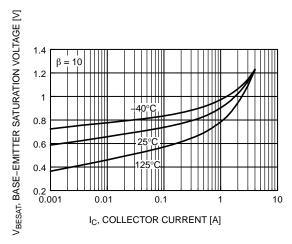
#### **ORDERING INFORMATION**

Part Number	Top Mark	Package	Shipping <sup>†</sup>
FZT790A	790A	SOT-223 (Pb-Free)	4,000 Units/ Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### FZT790A

#### **TYPICAL PERFORMANCE CHARACTERISTICS**





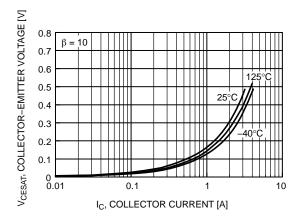


Figure 3. Collector–Emitter Saturation Voltage vs. Collector Current

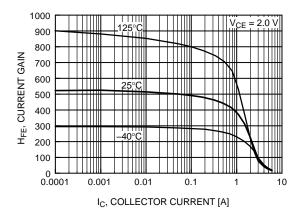


Figure 5. Current Gain vs. Collector Current

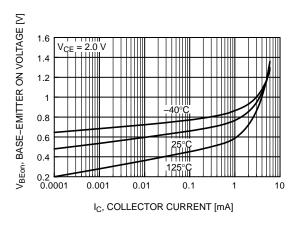


Figure 2. Base–Emitter On Voltage vs. Collector Current

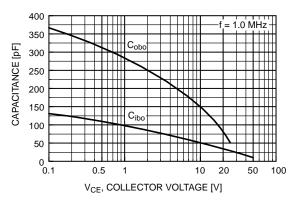
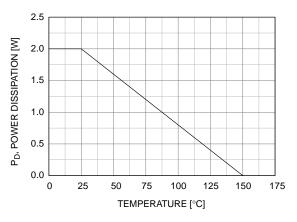
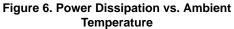


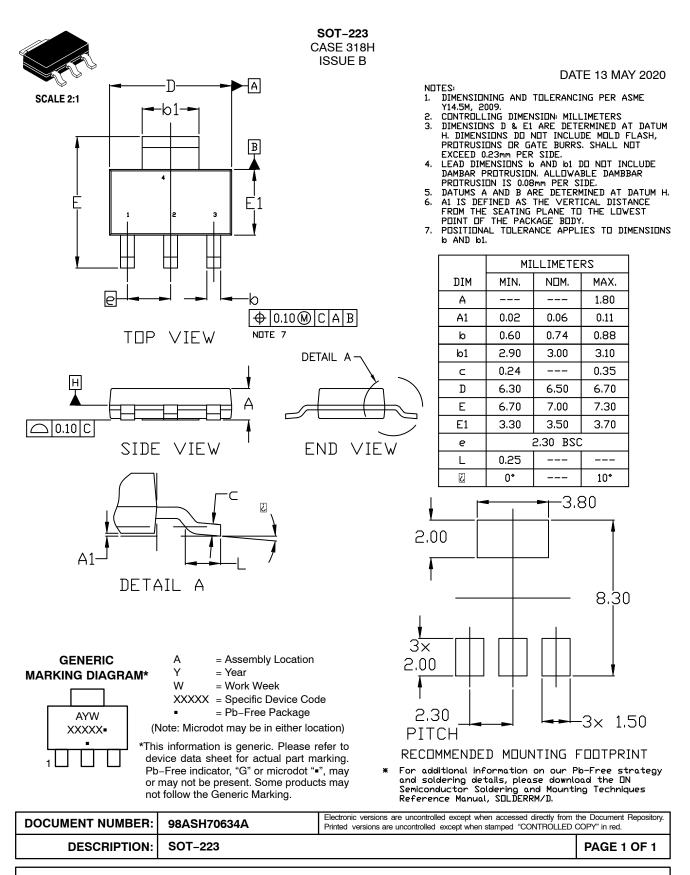
Figure 4. Input/Output Capacitance vs. Reverse Bias Voltage





## onsemi

PACKAGE DIMENSIONS



onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent\_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>